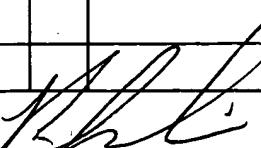


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Sheet 1 of 1

Form PTO-1449 (REV. 8-83)			US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 125209	APPLICATION NO. New U.S. National Stage of PCT/JP2004/000567	
INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)							
			APPLICANTS Satoshi SUGAHARA et al.				
			FILING DATE September 2, 2005				
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME		CLASS	SUB CLASS
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY		CLASS	SUB CLASS
BPS	1	JP A 2001-250998 w/abstr. + trans.	09/14/2001	Japan			
	2	JP A 2001-93274 w/abstr. + trans.	04/06/2001	Japan			
	3	JP A 10-284765 w/abstr. + trans.	10/23/1998	Japan			
	4	JP A 2004-111904 w/abstr. + trans.	04/08/2004	Japan			
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)							
	5	Inomata, "Present and Future of Magnetic RAM Technology," IEICE Trans. Electron, Vol. E84-C, No. 6, pp. 740-746, June 2001					
EXAMINER					DATE CONSIDERED 11/21/06		
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

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